L Number	Hits	Search Text	DB	Time stamp
1 Number		349/43	USPAT;	2004/08/04 13:56
	1001	347/43	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
2	1593	349/149-152.ccls.	USPAT;	2004/08/04 13:57
2	1373	349/149 132.0015.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
3	461	349/149-152.ccls. and ((contact adj hole)	USPAT;	2004/08/04 13:58
	101	opening)	US-PGPUB;	
		oponing,	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
4	203	349/149-152.ccls. and ((contact adj hole)	USPAT;	2004/08/04 13:58
-		opening) and input	US-PGPUB;	
]			EPO; JPO;	
			DERWENT;	
			IBM TDB	
5	1225	349/43 and ((contact adj hole) opening)	USPAT;	2004/08/04 13:59
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
6	71	349/43 and 349/149-152.ccls. and ((contact	USPAT;	2004/08/04 15:58
		adj hole) opening)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
7	7338	pixel near10 ((contact adj hole) opening)	USPAT;	2004/08/04 15:58
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	[
			IBM_TDB	
8	2311	(pixel near10 ((contact adj hole) opening))	USPAT;	2004/08/04 15:59
		and 349/.ccls.	US-PGPUB;	
			EPO; JPO;	
l			DERWENT;	
			IBM_TDB	
9	50		USPAT;	2004/08/04 16:01
		and 349/43 and 349/149-152.ccls.	US-PGPUB;	
			EPO; JPO;	1
			DERWENT;	1
			IBM_TDB	2224/22/24 15 21
11	64	(pixel near10 ((contact adj hole) opening))	USPAT;	2004/08/04 16:01
		and (input adj line)	US-PGPUB;	
1			EPO; JPO;	
			DERWENT;	
	1100	240/42	IBM_TDB USPAT;	2003/08/12 16:59
-	1199	349/43	US-PGPUB;	2003/00/12 10:39
]			EPO; JPO;	
1			DERWENT;	
			IBM TDB	
_	1340	349/149	USPAT;	2003/08/12 17:00
-	1240	J=7/ ±=7	US-PGPUB;	=====================================
			EPO; JPO;	1
			DERWENT;	[
			IBM TDB]
_	1346	349/113	USPAT;	2003/08/12 17:00
	1310	5 - 5 - 5 - 5 - 5 - 5 - 5 - 5 - 5 - 5 -	US-PGPUB;	
			EPO; JPO;	
]			DERWENT;	
			IBM TDB	
_	239	349/114	USPAT;	2003/08/12 17:05
]	233		US-PGPUB;	
į			EPO; JPO;	
			DERWENT;	
			IBM TDB]
				L

-	100	349/159	USPAT;	2003/08/12 17:05
			US-PGPUB;	
-			EPO; JPO; DERWENT;	
			IBM TDB	
_	168	349/162	USPAT;	2003/08/12 17:05
	100	345/102	US-PGPUB;	2003, 00, 22 2 1 1 0 1
-			EPO; JPO;	ł
			DERWENT;	1
			IBM_TDB	1
-	233	345/80	USPAT;	2003/08/12 17:06
			US-PGPUB;	
			EPO; JPO;	
	-		DERWENT;	
	205	245/00	IBM_TDB	2003/08/12 17:07
-	805	345/90	USPAT; US-PGPUB;	2003/08/12 17:07
			EPO; JPO;	
ļ			DERWENT;	
			IBM TDB	
_	3682313	(line or LOG)	USPAT;	2003/08/12 17:09
	30000	(12.00 00 000)	US-PGPUB;	
1			EPO; JPO;	
	Į		DERWENT;	
			IBM_TDB	
-	95863	(line or LOG)and (liquid adj crystal)	USPAT;	2003/08/12 17:10
			US-PGPUB;	
	ŀ		EPO; JPO;	
1			DERWENT;	
	50000	(3/22 22 700) and (3/22/4 add amortal) and	IBM_TDB	2002/00/12 17:10
-	59030	(line or LOG) and (liquid adj crystal) and	USPAT; US-PGPUB;	2003/08/12 17:10
	1	driv\$4	EPO; JPO;	
			DERWENT;	
	1		IBM TDB	
_	0	(line or LOG) and (liquid adj crystal) and	USPAT;	2003/08/12 17:12
!		driv\$4 and (double-layer) and (AlNd adj	US-PGPUB;	
		alloy)	EPO; JPO;	
		-	DERWENT;	
	ļ		IBM_TDB	
-	85	(line or LOG) and (liquid adj crystal) and	USPAT;	2003/08/12 17:12
		driv\$4 and (double-layer) and ((AlNd adj	US-PGPUB;	
		alloy) or Mo)	EPO; JPO;	
]			DERWENT; IBM TDB	
	50	(line or LOG) and (liquid adj crystal) and	USPAT;	2003/08/12 17:13
-	30	driv\$4 and (double-layer) and ((AlNd adj	US-PGPUB;	
		alloy) or Mo) and Cr	EPO; JPO;	
1			DERWENT;	
			IBM_TDB	
-	78	(line or LOG) and (liquid adj crystal) and	USPĀT;	2003/08/12 17:16
1		driv\$4 and (double-layer) and ((AlNd adj	US-PGPUB;	
		alloy) or Mo or molybdenum) and (Cr or	EPO; JPO;	
	1	chromium)	DERWENT;	
	_	(1) TOO	IBM_TDB	2002/00/12 17:10
-	2	(line or LOG) and driv\$4 and (double-layer)	USPAT; US-PGPUB;	2003/08/12 17:18
1	1	and ((AlNd adj alloy) or Mo or molybdenum) and (Cr or chromium) and 349/149	EPO; JPO;	
		morybacitam/and (or or chromitam/ and 349/149	DERWENT;	
	1		IBM TDB	
_	1 1	(line or LOG) and driv\$4 and (double-layer)	USPAT;	2003/08/12 17:18
1	1	and ((AlNd adj alloy) or Mo or	US-PGPUB;	
	1	molybdenum) and (Cr or chromium) and 349/113	EPO; JPO;	
		and 349/114	DERWENT;	
!	1		IBM_TDB	
-	1120		USPAT;	2003/08/12 17:19
		and ((AlNd adj alloy) or Mo or	US-PGPUB;	
	1	molybdenum) and (Cr or chromium) and 349/113	EPO; JPO;	
	1	or transflect\$4	DERWENT;	
	1		IBM_TDB	

-	0	(line or LOG) and driv\$4 and (double-layer) and ((AlNd adj alloy) or Mo or	USPAT; US-PGPUB;	2003/08/12 17:19
		molybdenum) and (Cr or chromium) and 349/113 and transflect\$4	EPO; JPO; DERWENT;	
	0	(line or LOG)and driv\$4 and (double-layer)	IBM_TDB USPAT;	2003/08/12 17:20
j -	U	and ((AlNd adj alloy) or Mo or	US-PGPUB;	2003,00,12 17.20
		molybdenum) and (Cr or chromium) and 349/159	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2	(line or LOG) and driv\$4 and (double-layer)	USPAT;	2003/08/12 17:21
		and ((AlNd adj alloy) or Mo or	US-PGPUB;	
		molybdenum) and (Cr or chromium) and 349/162	<pre>EPO; JPO; DERWENT;</pre>	
			IBM TDB	
_	0	(line or LOG) and driv\$4 and (double-layer)	USPAT;	2003/08/12 17:21
		and ((AlNd adj alloy) or Mo or	US-PGPUB;	
		molybdenum) and (Cr or chromium) and 345/32	EPO; JPO;	
			DERWENT; IBM TDB	
	0	(line or LOG)and driv\$4 and (double-layer)	USPAT;	2003/08/12 17:21
_		and ((AlNd adj alloy) or Mo or	US-PGPUB;	2000,00,11
		molybdenum) and (Cr or chromium) and 345/80	EPO; JPO;	
			DERWENT;	
	_		IBM_TDB	2002/00/12 17:21
-	0	(line or LOG) and driv\$4 and (double-layer)	USPAT; US-PGPUB;	2003/08/12 17:21
		and ((AlNd adj alloy) or Mo or molybdenum) and (Cr or chromium) and 345/90	EPO; JPO;	
		morybaenamy and ter or enromitamy and 313730	DERWENT;	
ļ			IBM_TDB	
-	525	345/32	USPAT;	2003/08/12 17:21
1			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
_	7	(line or LOG) and (line with resistance) and	USPAT;	2003/08/12 17:26
		(drive\$4 with retard\$4) and (liquid adj	US-PGPUB;	
		crystal)	EPO; JPO;	
			DERWENT; IBM TDB	
	99	349/113 and 349/114	USPAT;	2003/08/13 17:27
_		313/113 and 313/111	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	252	(line on IOG) and (limit add amountal) and	IBM_TDB USPAT;	2004/08/02 14:35
-	252	(line or LOG)and (liquid adj crystal) and driv\$4 and (double-layer)	US-PGPUB;	2004/00/02 14.33
]		EPO; JPO;	
			DERWENT;	
			IBM_TDB	2002/00/12 10 02
-	183	(line or LOG) and (liquid adj crystal) and	USPAT; US-PGPUB;	2003/08/12 18:03
		driv\$4 and (double-layer) and insulat\$	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	38		USPAT;	2004/08/02 17:31
		driv\$4 and (double-layer) and insulat\$ and	US-PGPUB; EPO; JPO;	
		(line with resistance)	DERWENT;	
			IBM_TDB	
-	24	349/113 and 349/114 and (Cr or chromium)	USPAT;	2003/08/13 17:29
			US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
_	8	(line or LOG) and driv\$4 and (double-layer)	USPAT;	2003/08/13 18:03
		and ((AlNd adj alloy) or Mo or	US-PGPUB;	
		molybdenum) and (Cr or chromium) and 349/113	EPO; JPO;	
			DERWENT; IBM TDB	
1			T DIA T D D	

-	0	(line or LOG) and driv\$4 and (double-layer)	USPAT;	2003/08/13 18:18
		and ((AlNd adj alloy) or Mo or	US-PGPUB;	
		molybdenum) and (Cr or chromium) and ((gate	EPO; JPO;	
		adj line) and (data adj line) and (reflective	DERWENT; IBM TDB	
	107	adj electrode)) (line or LOG)and ((gate adj line)and (data	USPAT;	2003/08/14 14:33
-	107	adj line) and (reflective adj electrode))	US-PGPUB;	2003/00/14 14.33
		adj line, and (leffective adj electrode,)	EPO; JPO;	
			DERWENT;	i
			IBM TDB	
-	35562	(choo or chung).in.	USPAT;	2003/08/14 14:34
:			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		()	IBM_TDB	2003/08/14 14:34
-	t e	(choo or chung) in and (limit add arratal)	USPAT USPAT	2003/08/14 14:34
-	216 5	(choo or chung).in. and (liquid adj crystal) (choo or chung).in. and (liquid adj crystal)	USPAT	2003/08/14 14:33
-) 3	and transflect\$4 and reflect\$4	USFAI	2003/00/14 13.22
l _	1	6466280.pn.	USPAT	2003/08/14 15:22
_	18	(line or LOG) and driv\$4 and (double-layer)	USPAT;	2003/08/14 15:25
1		and ((AlNd adj alloy) or Mo or	US-PGPUB;	
		molybdenum) and (Cr or chromium) and 349/43	EPO; JPO;	
			DERWENT;	
			IBM_TDB	0004/00/10 10 11
-	9	(pixel near10 (contact adj hole)) near10	USPAT;	2004/03/18 10:44
		(drain and gate and reflect\$4) and (liquid	US-PGPUB; JPO	
	9	adj crystal) (pixel near10 (contact adj hole)) near10	USPAT:	2004/03/18 11:19
-	9	(drain and gate and reflect\$4)	US-PGPUB;	2004/03/10 11:13
		(drain and gate and refreety)	JPO	
_	13	(pixel with (drain and gate and reflect\$4))	USPAT;	2004/03/18 11:41
		near10 (contact adj hole\$4)	US-PGPUB;	
			JPO	
-	44	(pixel and (drain and gate and reflect\$4))	USPAT;	2004/03/18 11:41
		near10 (contact adj hole\$4)	US-PGPUB;	
		(2) (2) (3) (4) (4) (4) (4)	JPO	2004/08/02 16:41
-	113	(line or LOG)and (liquid adj crystal) and (line near10 signal near10 driv\$4) and	USPAT; US-PGPUB;	2004/08/02 16:41
		(double-layer)	EPO; JPO;	
		(double-layer)	DERWENT;	
			IBM TDB	
_	17112	(choo chung park).in.	USPAT	2004/08/02 16:42
-	735		USPAT	2004/08/02 16:43
		crystal)		
-	543	(choo chung park).in. and (liquid adj	USPAT	2004/08/02 16:44
	_	crystal) and (line near "10" structure)	, richam	2004/09/02 16:45
-	477	(choo chung park).in. and (liquid adj	USPAT	2004/08/02 16:45
		crystal)and (line near "10" structure)and ((line on glass) LOG)		
1_	20814	1 1 1 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2	USPAT	2004/08/02 16:46
_	20014	structure) and ((line on glass) LOG) and drive		
-	121	1	USPAT	2004/08/02 16:47
		structure) and ((line on glass) LOG) and drive		
		and (refelct\$4 transflect\$4)		
-	132		USPAT	2004/08/02 16:51
		crystal) and (line near "10" structure) and		
		((line on glass) LOG) and drive	HODAM	2004/00/02 16 10
-	329		USPAT; US-PGPUB;	2004/08/02 16:48
		structure) and ((line on glass) LOG) and drive	EPO; JPO;	1
	1	and (refelct\$4 transflect\$4)	DERWENT;	
			IBM TDB	
_	280	(liquid adj crystal)and (line near "10"	USPAT;	2004/08/02 16:48
		structure) and ((line on glass) LOG) and drive	US-PGPUB;	
		and (refelct\$4 transflect\$4) and pixel	EPO; JPO;	
			DERWENT;	
			IBM_TDB	

-	44	(liquid adj crystal)and (line near "10"	USPAT;	2004/08/02 16:48
		structure) and ((line on glass) LOG) and drive	US-PGPUB;	
		and (refelct\$4 transflect\$4) and pixel and	EPO; JPO;	
		passivation	DERWENT;	
			IBM TDB	
_	23	(choo chung park).in. and (liquid adj	USPAT	2004/08/02 16:51
		crystal) and (line near "10" structure) and		
		((line on glass) LOG) and drive and LG.as.		
-	13		USPAT;	2004/08/02 17:20
		structure) and ((line on glass) LOG) and drive	US-PGPUB;	
		and (refelct\$4 transflect\$4) and pixel and	EPO; JPO;	
		passivation and (contact adj hole)	DERWENT;	
	[passivacion and (consuct any neity)	IBM TDB	
	25	(liquid adj crystal) and drive and (refelct\$4	USPAT;	2004/08/02 17:15
_	23	transflect\$4) and pixel and passivation and	US-PGPUB;	2001,00,02 1,113
		(contact adj hole)	EPO; JPO;	
		(concast adj note)	DERWENT;	
	İ		IBM TDB	
_	1	6466280.pn.	USPAT	2004/08/02 17:15
_	58		USPAT;	2004/08/02 17:32
-	30	driv\$4 and (double-layer) and insulat\$ and	US-PGPUB;	2004/00/02 17:32
		(line with resistance)	EPO; JPO;	
		(line with resistance)	DERWENT;	
	1			
		//inch add 1inc) manual /finch and come	IBM_TDB	2004/08/03 08:50
-	52		USPAT;	2004/08/03 08:59
		and third)) and 345/\$.ccls.	US-PGPUB;	
			EPO; JPO; DERWENT;	
			,	
		(/inch and lime) manual (final and second	IBM_TDB	2004/08/03 09:01
-	6	((input adj line) near10 (first and second	USPAT;	2004/08/03 09:01
		and third)) and 349/\$.ccls.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		(()	IBM_TDB	2004/08/22 22 23
-	65	((input adj line) and (first and second and	USPAT;	2004/08/03 09:24
		third)) and 349/\$.ccls.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		1 (()	IBM_TDB	2004/00/02 00 54
-	18	' ' = - E	USPAT;	2004/08/03 09:24
		third)) and 349/149	US-PGPUB;	
			EPO; JPO;	
	1		DERWENT;	
		1,,,	IBM_TDB	0004/00/00 00 00
-	12		USPAT;	2004/08/03 09:26
	1	third)) and 349/152	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	1